# **Product Preview**

# **80 V Power MOSFET**

ON Semiconductor utilizes its latest MOSFET technology process to manufacture 80 V power MOSFET devices to achieve the lowest possible on–resistance per silicon area. These 80 V devices are designed for Power Management solutions in 42 V Automotive system applications. Typical applications include integrated starter alternator, electronic power steering, electronic fuel injection, catalytic converter heaters and other high power applications made possible via an automotive 42 V bus. ON Semiconductor's latest technology offering continues to offer high avalanche energy capability and low reverse recovery losses.



 $(T_{.1} = 25^{\circ}C \text{ unless otherwise noted})$ 

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	V(BR)DSS	00			Vdc	
$(V_{GS} = 0 \text{ Vdc}, I_D = 250 \mu\text{Adc})$		80	_			
Zero Gate Voltage Drain Current (VDS = 80 Vdc, VGS = 0 Vdc) (VDS = 80 Vdc, VGS = 0 Vdc, TJ = 150°C)	I <sub>DSS</sub>	- -	- -	1.0 10	μAdc	
Gate-Body Leakage Current (VGS = ±20 Vdc, VDS = 0 Vdc)	IGSS	_	_	±100	nAdc	

#### **ON CHARACTERISTICS**

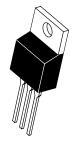
Gate Threshold Voltage (V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μAdc) NTP/B70N08 NTP/B70N08L	VGS(th)	2.0 1.0	3.0 1.5	4.0 2.0	Vdc
Static Drain-to-Source On-Resistance (ID = 35 Adc) NTP/B70N08, VGS= 10 V NTP/B70N08L, VGS = 5 V	RDS(on)	_ _	19 21	_ _	mΩ



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70 AMPERES 70N08 Typ RDS(on) = 19 m $\Omega$  70N08L Typ RDS(on) = 21 m $\Omega$ 





TO-220 (XTP) CASE 221A-09 STYLE 5

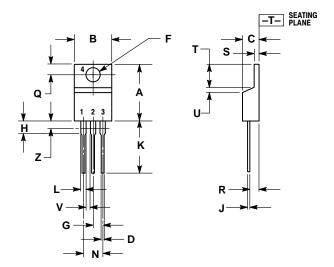


D<sup>2</sup>PAK (XTB) CASE 418B STYLE 2

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

# **PACKAGE DIMENSIONS**

TO-220 CASE 221A-09 **ISSUE AA** 

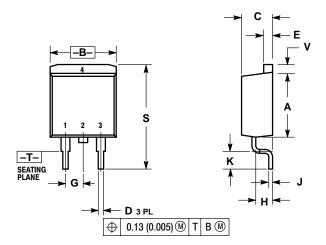


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

- STYLE 5:
  PIN 1. GATE
  2. DRAIN
  3. SOURCE
  4. DRAIN

D<sup>2</sup>PAK CASE 418B-03 ISSUE D



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
Е	0.045	0.055	1.14	1.40
G	0.100 BSC		2.54 BSC	
H	0.080	0.110	2.03	2.79
7	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
S	0.575	0.625	14.60	15.88
٧	0.045	0.055	1.14	1.40

STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

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